



## China-Japan Mini Workshop on SOIPIX

Thursday, 14 July 2016

Session 3 - A419 (14:00 - 15:40)

-Conveners: Qun OUYANG

| time  | [id] title  | presenter     |
|-------|---|---------------|
| 14:00 | [6] Radiation hardness improvement of FD-SOI MOSFETs for X-ray detector application | KARACHI, Ikuo |
| 14:25 | [7] A counting type SOI chip and synchrotron beam test results                      | LU, Yunpeng   |
| 14:50 | [8] Design of First China-Japan Counting Pixel (CNPIX1)                             | ARAI, Yasuo   |
| 15:15 | [9] EMC problems of DSOI device and circuits  | LI, Binhong   |